



Chapter 13: Transport properties of optically driven molecular switches

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Outline

• Foundations

- Controllable Single-Molecule Junctions: Break Junction Technique
- Analysis of current-voltage characteristics: Resonant Level Model
- Inelastic Electron Tunneling Spectroscopy: Revealing junction configuration and some information on transmission coefficients
- Optically activated molecular switches
 <u>Azobenzenes</u>: Fano resonance
 <u>Diarylethenes</u>: Unconventional behavior of level alignment



Understanding IVs: Single-Level Model



$$I(V) = \frac{2e}{h} \int_{-\infty}^{\infty} T(E,V) [f(E-eV/2) - f(E+eV/2)] dE$$
 Landauer formula

L. Zotti, Th. Kirchner, J. C. Cuevas, F. Pauly, Th. Huhn, J. Wolf, E. Scheer, A. Erbe, SMALL **6**, 1529 (2010)

$$T(E,V) = \frac{4\Gamma_{L}\Gamma_{R}}{[E - E_{0}(V)]^{2} + [\Gamma_{L} + \Gamma_{R}]^{2}}$$

See also: Huisman et al., Nano Lett. **9**, 3909 (2009)



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L. Zotti, Th. Kirchner, J. C. Cuevas, F. Pauly, Th. Huhn, J. Wolf, E. Scheer, A. Erbe, SMALL 6, 1529 (2010) See also: Huisman et al., Nano Lett. 9, 3909 (2009) $T(E,V) = \frac{4\Gamma_L \Gamma_R}{[E - E_0(V)]^2 + [\Gamma_L + \Gamma_R]^2}$



(Off-)resonant tunneling

Asymmetric coupling : Asymmetric I-Vs

if
$$\alpha = \Gamma_R / \Gamma_L$$

Off resonant case: molecules as tunneling junctions



L. Zotti et al, Small 6 1529 (2010)

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Resonant level model



Assumption: HOMO and LUMO well-separated $E_{LUMO}-E_{HOMO} >> \Gamma$



$$I(E,V) = \frac{1}{[E - E_{HOMO}]^2 + 4\Gamma_{HOMO}^2} + \frac{1}{[E - E_{LUMO}]^2 + 4\Gamma_{LUMO}^2}$$

L. Zotti et al., Small **6**, 1529 (2010), E. Huisman et al., Nano Lett. **9**, 3909 (2009), W. Hong et al. Beilstein J. Nanotechology (2012),





Current-voltage characteristics and the single-level model: The role of the end-group / metal combination

L. Zotti, Th. Kirchner, J. C. Cuevas, F. Pauly, Th. Huhn, J. Wolf, A. Erbe, Small 6, 1529 (2010)

- Y. Kim, H. Song, F. Strigl, H.-F. Pernau, T. Lee, E. Scheer, Phys. Rev. Lett. **106**, 196804 (2011).
- Y. Kim, Th. Hellmuth, M. Bürkle, F. Pauly, E. Scheer, ACS Nano 5, 4104 (2011).





Liquid MCBJ

Characterization of molecules in liquid environment





See also: L. Grüter et al., Small 1, 1067 (2005)



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Role of linker groups: simple molecules

- Basic molecule: Bis-tolane
- Conjugated => conductive
- Change of linker groups



BTT: Bis-thiotolane



BCT: Bis-cyanotolane







IV curves with various linkers



L. Zotti, Th. Kirchner, J. C. Cuevas, F. Pauly, Th. Huhn, J. Wolf, E. Scheer, A. Erbe, SMALL 6, 1529 (2010)

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Statistical comparison of linkers

 O_2N

-NO₂

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L. Zotti, Th. Kirchner, J. C. Cuevas, F. Pauly, Th. Huhn, J. Wolf, E. Scheer, A. Erbe, SMALL 6, 1529 (2010)



Transmission function of molecular junctions

- Quantum chemistry & DFT
- Approximation to single Lorentzian valid
- Linkers determine nature of transport
- BTT & BAT: HOMO
- BNT & BCT: LUMO



L. Zotti, Th. Kirchner, J. C. Cuevas, F. Pauly, Th. Huhn, J. Wolf, E. Scheer, A. Erbe, SMALL 6, 1529 (2010)



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MCBJ at low temperature: Opening Traces and Conductance Histograms



Y. Kim, F. Strigl, H.-F. Pernau, H. Song, T. Lee, E. Scheer, Phys. Rev. Lett. 106, 196804 (2011)



Inelastic Electron Tunneling Spectroscopy (IETS)



M. A. Reed, Mat. Today (2008), Troisi & Ratner, Small (2008), Arroyo et al., Nano Lett. (2010)¹⁵



Examples: I-Vs and IETS @ 4.2 K



Au-HDT-Au: $\Gamma_{L,R} = 120 \text{ meV}, E_0 = 2.35 \text{ eV}$ Pt-HDT-Pt: $\Gamma_{L,R} = 110 \text{ meV}, E_0 = 1.93 \text{ eV}$



Au-HDT-Au under stretching



-> Not all modes observable in any configuration



Assignment of modes





Role of contact metal: Pt-HDT-Pt vs. Au-HDT-Au



Amplitude of Au phonon mode increases, Pt mode remains constant Energy of Au-S mode constant, Pt-S: "guitar string" -> chain formation for Au, no chains for Pt 19

Y. Kim, F. Strigl, H.-F. Pernau, H. Song, T. Lee, E. Scheer, Phys. Rev. Lett. 106, 196804 (2011)





I-Vs and IETS of model molecules under stretching



Y. Kim, Th. Hellmuth, M. Bürkle, F. Pauly, E. Scheer, ACS Nano 5, 4104 (2011). Au chain formation with ODT

Role of the binding group: ODA and ODT on Au electrodes



Y. Kim, Th. Hellmuth, M. Bürkle, F. Pauly, E. Scheer, ACS Nano 5, 4104 (2011).



Role of the binding group: ODA and ODT on Au electrodes







Role of the binding group: ODA and ODT on Au electrodes



Y. Kim, Th. Hellmuth, M. Bürkle, F. Pauly, E. Scheer, ACS Nano 5, 4104 (2011).





Example IETS of ODA @ 4.2 K



Y. Kim, Th. Hellmuth, M. Bürkle, F. Pauly, E. Scheer, ACS Nano 5, 4104 (2011).

Linewidth broadening of IETS of ODA Monstanz





Experimental linewidth W_{exp} given by intrinsic linewidth W_{I} , thermal broadening $k_{B}T$ and modulation voltage V_{ac} : $W_{exp} = [(5.4k_{B}T)^{2} + (1.7V_{ac})^{2} + (W_{I})^{2}]^{1/2}$

 a) V dependence at fixed T: black line: linear fit ->W_I = 4.9 ± 0.8 meV
 b) T dependence at fixed V_{ac}: black squares: theoretical expectation, red dots: experimental findings
 T = 4K: 5.4k_PT = 1.8meV



Stretching dependence of IETS



Au-Amine bond weakens upon stretching, short stretching length Au-Thiol bond robust -> formation of a gold chain

Y. Kim, Th. Hellmuth, M. Bürkle, F. Pauly, E. Scheer, ACS Nano 5, 4104 (2011).



BDT: Analysis of I-Vs and IETS for revealing electronic structure



Y. Kim, T. Pietsch, A. Erbe, W. Belzig, E. Scheer, Nano Lett. 11, 3734 (2011)







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Au-BDT-Au: highly conductive and non-symmetric coupling possible



$$E_0(V) = E_0 + \left(\frac{\Gamma_L - \Gamma_R}{\Gamma_L + \Gamma_R}\right) \frac{eV}{2} \qquad \alpha = \Gamma_R / \Gamma_L$$



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I-Vs of Au-BDT-Au: wide conductance range



Quantitative agreement with GW calculations: $E_0 = 0.3 \text{ eV}$ Strange et al., Phys. Rev.B **83**, 115108 (2011)



PCS vs. IETS: Sign change of d²I/dV²



Experiments: Tal *et al*. PRL **100** 196804 (2009)

Pt/H₂O

- $0.2 < G/G_0 < 1.2$
- Sign change observed ~0.6 G₀
- -> 2-channel contacts

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Tal et al. PRL 100 196804 (2009)
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dl/dV & IETS spectra in wide conductance range





Transition from PCS to IETS in Au-BDT-Au





Summary I

- Single-level model successfully describes the I-Vs of singlemolecule junctions of "simple molecules" in a wide conductance range.
- Microscopic parameters E_0 and Γ can be deduced and compared with ab initio results.
- Variable electrodes & IETS enable to reveal junction configuration and influence of anchor group and electrode material)



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Towards optically driven molecular switches

<u>Goal:</u> Reversible conductance switching of a single-molecule junction by light <u>Issues:</u>

- Conductance, junctions, suitable molecules
- Role of electrodes: Optical antennae?
 - D. Guhr et al., PRL 99, (2007)
 - D. Benner et al., NJP, 2013



D. Sysoiev et al., Chem. Eur. J. 17, 6663 (2011)
Y. Kim et al., Nano Letters 12, 3736 (2012)
B.M. Briechle et al., Beilstein J. Nanotech. 3, 703 (2012)
D. Sysoiev et al., Chem. Commun. 48, 11355 (2012)
Y. Kim et al., Phys. Rev. Lett. 109, 226801 (2012)



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Towards optically driven molecular switches

Requirements:

- Bind reliably & specifically
- Switches reliably between two states
- No or small length change upon switching
- Sufficient flexibility to adopt to electrode gap
- High quantum yield for switching
- Two states clearly distinguishable
- Reasonable current level in both states



J. T. State

Light-induced conductance switching of Diarylethenes



Irreversible off-switching

D. Dulic et al., Phys. Rev. Lett. 91, 207402 (2003)







Measurements on ensembles of molecules



Reversible optically-driven switching observed on ensembles





Light-induced Conductance Switching of Molecules



Ar atmosphere, RT

S.J. van der Molen, Nano Lett. 9, 76 (2009) 40



Single-Molecule Light-induced Conductance Switching : CNT electrodes



Extension of π system reduces quantum yield Irreversible switching for thiophene switch (species 1) Species 2

A.C. Whalley et al, JACS 129, 12590 (2007) 41



Sulfur-free photochromic molecules









Surface-plasmon resonance

Thiol-terminated dry molecule/Au

 $\lambda = 980 \text{ nm}$ d = 47 nm





Thiol-terminated dry molecule/Au



Equivalent findings for TSC, 4Py, MN, RN, MTSC, CHO, THM, YNPh









Experiment: Conductance at 4K





J. T. State

Single-molecule transport at 4 K



Closed co	nductar	nce (10 ⁻⁷	G ₀):			
50	>	8	~	13	>	8
Switching	ratio:					
38	>	10	~	12	>	6



Experiment: I-Vs at 4K





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Experiment: I-Vs at 4K







IETS: Shift of N-N stretching mode



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Level alignment: HOMO/LUMO switching?





Theory: Transmission function





Conductance Switching at 230 K

4Py

 0.05 mW/cm^2

TSC







Single-molecule switching



M. Irie, *Photoreactive materials for ultrahigh-density optical memory*, Elsevier: Amsterdam, 1994
B. Feringa, *Molecular Switches*, 2nd edition, VCH-Verlag, 2011



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Further optimization of switching properties



D. Sysoiev et al., Chem. Commun. 48, 11355 (2012)

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Azobenzene switches









M. Comstock et al, Phys. Rev. Lett. 99, 038801 (2007) 58

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M. Mativetsky et al, JACS 130, 9210 (2008)





Azobenzene-based switches

Decoupling of switching core by CH2 group



Y. Kim, A. Garcia-Lekue, D. Sysoiev, T. Frederiksen, U. Groth, E. Scheer, PRL 109, 226801 (2012)⁶⁰





cis has higher conductance than trans: $G_{cis}/G_{trans} \sim 3$

Y. Kim, A. Garcia-Lekue, D. Sysoiev, T. Frederiksen, U. Groth, E. Scheer, PRL 109, 226801 (2012)





Fitting with single-level model : cis: $E_0 = 0.36 + / - 0.05 \text{ eV}, \Gamma = 0.28 + / - 0.1 \text{ meV}$ trans: $E_0 = 0.52 + / - 0.06 \text{ eV}, \Gamma = 0.26 + / - 0.06 \text{ meV}$

Y. Kim, A. Garcia-Lekue, D. Sysoiev, T. Frederiksen, U. Groth, E. Scheer, PRL 109, 226801 (2012)⁶²





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Y. Kim, A. Garcia-Lekue, D. Sysoiev, T. Frederiksen, U. Groth, E. Scheer, PRL 109, 226801 (2012)⁶³





Transmission function



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Transmission function



HOMO-1



Fano Resonance





Summary

- Lower conductance of *trans*-AzoTM caused by Fano resonance
- Unexpected electronic structure of conjugated diarylethene switches: Indication for switching from HOMO transport in open form to LUMO transport in closed form

Open Questions & Outlook

- Enhancing quantum yield and conductance!
- Making on/off switching ratio more symmetric
- Reversible optical switching of current in a single-molecule device at low temperature possible?
- Switching mechanism: direct photoexcitation or metal-mediated?
- Plasmon enhancement by antenna action of electrodes?